1 GHz wideband low-noise amplifier with bypassRev. 2 — 13 September 2011Pro

Product data sheet

Product profile 1.

1.1 General description

The BGU7042 MMIC is a 3.3 V wideband amplifier with bypass mode. It is designed specifically for high linearity, low-noise applications over a frequency range of 40 MHz to 1 GHz. It is especially suited for Set-Top Box applications.

The LNA is housed in a 6-pin SOT363 plastic SMD package.

1.2 Features and benefits

- Voltage supply of 3.3 V
- Internally biased
- Programmable between G_p = 10 dB and bypass
- Flat gain between 40 MHz and 1 GHz
- Noise figure of 3.8 dB
- High linearity with an IP3_O of 29 dBm
- 75 Ω input and output impedance
- Power-down during bypass mode
- Bypass mode current consumption < 5 mA</p>
- ESD protection > 2 kV Human Body Model (HBM) and >1.5 kV Charged Device Model (CDM) on all pins

1.3 Applications

- Terrestrial and cable Set-Top Boxes (STB)
- Silicon and "Can" tuners
- Personal and Digital Video Recorders (PVR and DVR)
- Home networking and in-house signal distribution



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1.4 Quick reference data

Table 1. Quick reference data

 $T_{amb} = 25 \ ^{\circ}C$; typical values at $V_{CC} = 3.3 \ V$; $Z_S = Z_L = 75 \ \Omega$; $R_{bias} = 7.5 \ \Omega$; 40 MHz $\leq f_1 \leq 1000 \ MHz$.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CC}	supply voltage	RF input AC coupled		3.1	3.3	3.5	V
I _{CC(tot)}	total supply current	G _p = 10 dB mode	[1]	-	38	-	mA
		bypass mode	<u>[1]</u>	-	3	-	mA
T _{amb}	ambient temperature			-10	-	+70	°C
NF	noise figure	G _p = 10 dB mode	[1]	-	3.8	-	dB
		bypass mode	<u>[1]</u>	-	2.5	-	dB
P _{L(1dB)}	output power at 1 dB gain compression	1 GHz; G _p = 10 dB mode	<u>[1]</u>	-	12	-	dBm
IP3 ₀	output third-order intercept point	G _p = 10 dB mode	[1][2]	-	29	-	dBm

[1] Mode depends on setting of V_{CTRL} ; see <u>Table 8</u>.

[2] The fundamental frequency (f₁) is 1000 MHz. The intermodulation product (IM3) is $2 \times f_2 - f_1$, where $f_2 = f_1 \pm 1$ MHz. Input power $P_i = -10$ dBm.

2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	RF_OUT		
2	V _{CC}		\mathbf{N}^{3}
3	n.c.		6-1
4	CTRL		
5	GND		5 4 sym141
6	RF_IN		

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BGU7042	-	plastic surface-mounted package; 6 leads	SOT363

4. Marking

Table 4. Marking codes			
Type number	Marking code	Description	
BGU7042	*VB	* = p : made in Hong Kong	
		* = W : made in China	
		* = t : made in Malaysia	

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5. Limiting values

Table 5. In accorda	Limiting values ance with the Absolute Ma	ximum Rating System (IEC 60134).				
Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage	RF input AC coupled		-0.6	3.5	V
V _{ctrl(Gp)}	power gain control voltage	pin CTRL	[1]	0	V _{CC}	V
I _{CC(tot)}	total supply current			-	60	mA
P _{tot}	total power dissipation	$T_{sp} \le 100 \ ^{\circ}C$	[2]	-	250	mW
Pi	input power	single tone		-	10	dBm
T _{stg}	storage temperature			-65	+150	°C
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-10	+70	°C
V _{ESD}	electrostatic discharge voltage	Human Body Model (HBM); according to JEDEC standard 22-A114E		2	-	kV
		Charged Device Model (CDM); according to JEDEC standard 22-C101B		1.5	-	kV

[1] $V_{ctrl(Gp)}$ must not exceed V_{CC}; I_{CTRL} must be limited to 5 mA (maximum).

[2] T_{sp} is the temperature at the solder point of the ground lead.

Remark: $V_{ctrl(Gp)}$ must not exceed V_{CC} ; I_{CTRL} must be limited to a maximum of 5 mA.

6. Thermal characteristics

Table 6.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point		240	K/W

7. Characteristics

Table 7. $T_{amb} = 25$	Characteristics 5 °C; typical values at V _{CC} = 3.3 V;	$Z_S = Z_L = 75 \ \Omega; \ R_{bias} = 7.$	5Ω,	; 40 M	Hz ≤ f;	ı ≤ 100	0 MHz
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CC}	supply voltage	RF input AC coupled		3.1	3.3	3.5	V
I _{CC(tot)}	total supply current	$G_p = 10 \text{ dB mode}$	[1]	-	38	-	mA
		bypass mode	[1]	-	3	-	mA
$ s_{21} ^2$	insertion power gain	G _p = 10 dB mode	[1]	-	10	-	dB
		bypass mode	[1]	-	-2	-	dB
SL _{sl}	slope straight line	G _p = 10 dB mode		-	-1	-	dB
FL	flatness of frequency response	G _p = 10 dB mode		-	0.2	-	dB
NF	noise figure	$G_p = 10 \text{ dB mode}$	[1]	-	3.8	-	dB
		bypass mode	[1]	-	2.5	-	dB

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Table 7.	Characteristics	continued
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 $T_{amb} = 25 \ ^{\circ}C$; typical values at $V_{CC} = 3.3 \ V$; $Z_S = Z_L = 75 \ \Omega$; $R_{bias} = 7.5 \ \Omega$; 40 MHz $\leq f_1 \leq 1000 \ MHz$.

anno		0 2 , 5,40	,				
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
RL _{in}	input return loss	$G_p = 10 \text{ dB mode}$	[1]	-	21	-	dB
		bypass mode	[1]	-	10	-	dB
RL _{out}	output return loss	G _p = 10 dB mode	[1]	-	12	-	dB
		bypass mode	[1]	-	10	-	dB
$P_{L(1dB)}$	output power at 1 dB gain compression	1 GHz; G _p = 10 dB mode	[1]	-	12	-	dBm
IP3 ₀	output third-order intercept point	G _p = 10 dB mode	[1][2]	-	29	-	dBm
		bypass mode	[1][2]	-	29	-	dBm

[1] Mode depends on setting of $V_{ctrl(Gp)}$ (V_{CTRL}); see <u>Table 8</u>.

[2] The fundamental frequency (f₁) is 1000 MHz. The intermodulation product (IM3) is $2 \times f_2 - f_1$, where $f_2 = f_1 \pm 1$ MHz. Input power $P_i = -10$ dBm.

Table 8. Gain selection (pin CTRL)

 $-10 \text{ °C} \leq T_{amb} \leq +70 \text{ °C}$; recommended power-up condition: V_{CTRL} = logic 0 or < 0.7 V.

V _{ctrl(Gp)} (V _{CTRL}) (V)	Mode
≤ 0.7	bypass
≥ 1.5	$G_p = 10 \text{ dB}$

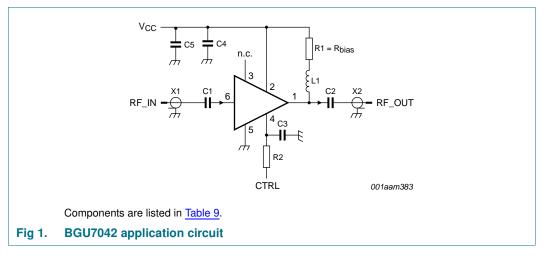
Remark: V_{ctrl(Gp)} must not exceed V_{CC}; I_{CTRL} must be limited to a maximum of 5 mA.

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8. Application information

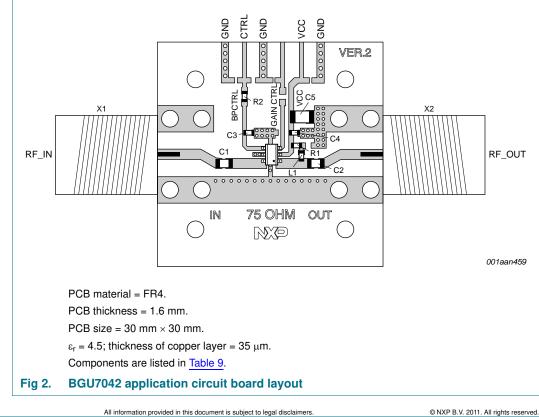
Other applications are possible. Please contact your local sales representative for more information. Application notes are available on the NXP website.

8.1 Application circuit



All control and supply lines must be decoupled properly. The decoupling capacitors must be placed as close to the device as possible.

8.2 Application circuit board layout



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Table 9.List of componentsSee Figure 1 and Figure 2

Description	Value		Remarks	Function
capacitor	10 nF			DC blocking
capacitor	10 nF			decoupling
capacitor	10 μF			decoupling
chip ferrite bead	1.5 kΩ	[1]	Murata BLM18HE152SN1DF	RF choke
resistor	7.5 Ω	[1]	R _{bias}	bias setting
resistor	1.8 kΩ			current limiting
connector	75 Ω		F-connector, edge mount PCB reflow type, Bomar 861V509ER6	input/output
	eapacitor eapacitor eapacitor enip ferrite bead esistor esistor	capacitor10 nFcapacitor10 nFcapacitor10 μ Fchip ferrite bead1.5 k Ω esistor7.5 Ω esistor1.8 k Ω	apacitor10 nFapacitor10 nFapacitor10 μ Fapacitor10 μ Fsapacitor1.5 k Ω thip ferrite bead1.5 k Ω esistor7.5 Ω 1.8 k Ω	apacitor10 nFapacitor10 nFapacitor10 μ Fstapacitor10 μ Fstapacitor1.5 k Ω [1]Murata BLM18HE152SN1DFesistor7.5 Ω [1]R_biasconnector75 Ω F-connector, edge mount PCB

[1] L1 and R1 must have a power rating of 0.1 W or higher.

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9. Package outline

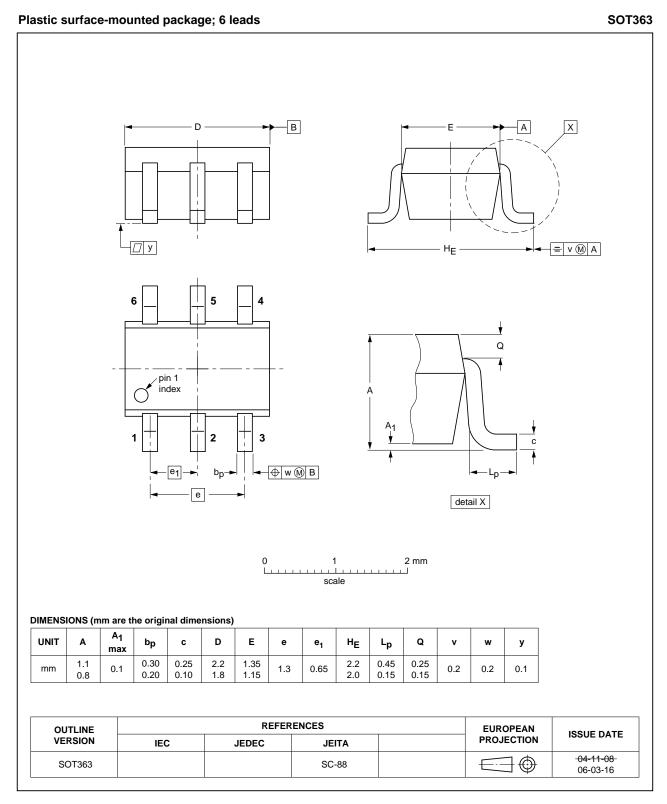


Fig 3. Package outline SOT363

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10. Abbreviations

Table 10. Ab	Table 10. Abbreviations		
Acronym	Description		
AC	Alternating Current		
DC	Direct Current		
ESD	ElectroStatic Discharge		
LNA	Low-Noise Amplifier		
MMIC	Monolithic Microwave Integrated Circuit		
PCB	Printed-Circuit Board		
RF	Radio Frequency		
SMD	Surface-Mounted Device		

11. Revision history

Table 11. Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
BGU7042 v.2	20110913	Product data sheet		BGU7042 v.1	
Modifications:	 Noise figure 	e value updated			
BGU7042 v.1	20110208	Product data sheet	-	-	

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12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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